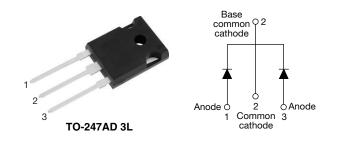
Hyperfast Rectifier, 2 x 15 A FRED Pt[®] G5



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LINKS TO ADDITIONAL RESOURCES



30	
0 Models	Appli No

PRIMARY CHARACTERISTICS						
I _{F(AV)} , per leg	15 A					
V _R	1200 V					
V _F at I _F at 125 °C	2.1 V					
t _{rr}	29 ns					
T _J max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

FEATURES

- Hyperfast and optimized Q_{rr}
- · Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage, per leg	V _{RRM}		1200	V			
Average rectified forward current, per leg	I _{F(AV)}	T _C = 111 °C, D = 0.50	15				
Repetitive peak forward current, per leg	I _{FRM}	T _C = 111 °C, D = 0.50, f = 20 kHz	30	А			
Non-repetitive peak surge current, per leg	I _{FSM}	T_{C} = 45 °C, t_{p} = 10 ms, sine wave	110				
Operating junction and storage temperature	TJ, T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL TEST CONDITIONS			TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage, per leg	V _{BR} , V _R	I _R = 100 μA	1200	-	-			
Forward voltage, par log	V	I _F = 15 A	-	2.5	3.3	V		
Forward voltage, per leg	V _F	I _F = 15 A, T _J = 125 °C	-	2.1	-			
Deverse leakage eurrent ner leg		$V_{R} = V_{R}$ rated	-	-	50			
Reverse leakage current, per leg	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance, per leg	CT	V _R = 200 V	-	10	-	pF		
Series inductance, per leg	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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RoHS COMPLIANT

HALOGEN FREE

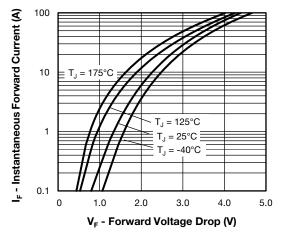


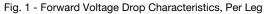
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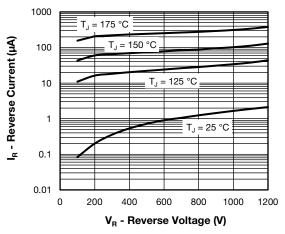
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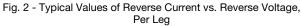
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
		1 A, 30 V, 100 A/µ	S	-	29	-			
Reverse recovery time, per leg	t _{rr}	T _J = 25 °C		-	96	-	ns		
		T _J = 125 °C		-	137	-			
Peak recovery current, per leg	1	T _J = 25 °C	I _F = 10 A dI _F /dt = 600 A/μs V _R = 400 V	-	11.5	-	A		
Feak recovery current, per leg	I _{RRM}	T _J = 125 °C		-	16	-			
Poverse recovery charge, per leg	0	T _J = 25 °C		-	375	-	nC		
Reverse recovery charge, per leg	Q _{rr}	T _J = 125 °C		-	900	-			
Reverse recovery time, per leg	+	T _J = 25 °C		-	77.5	-	ns		
neverse recovery time, per leg	t _{rr}	T _J = 125 °C		-	106	-	115		
Poak receivery ourrent per leg	1	T _J = 25 °C	$I_{\rm F} = 15 {\rm A}$	-	21	-	А		
Peak recovery current, per leg	I _{RRM}	T _J = 125 °C	dI _F /dt = 1000 A/µs V _B = 800 V	-	29	-			
	0	T _J = 25 °C		-	680	-			
Reverse recovery charge, per leg	Q _{rr}	T _J = 125 °C		-	1600	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case, per leg	R _{thJC}		-	-	1.4	°C/W		
Weight			-	6.0	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-247AD 3L	C5PX3012LH					









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VS-C5PX3012LHN3

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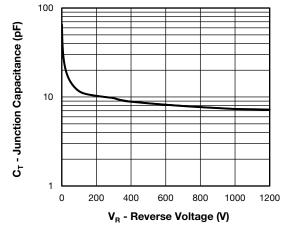


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

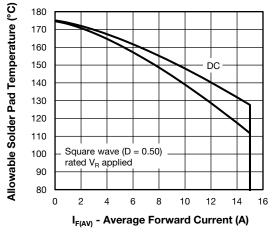


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

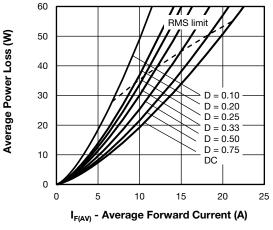


Fig. 5 - Forward Power Loss Characteristics, Per Leg

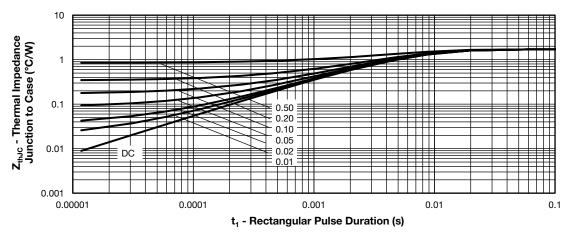
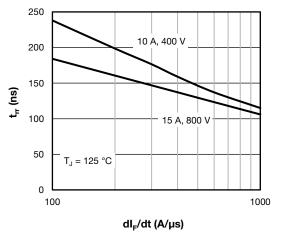


Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg

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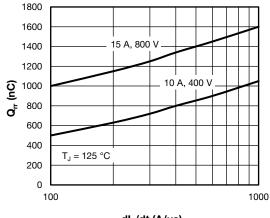




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Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg



dl_F/dt (A/µs)

Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

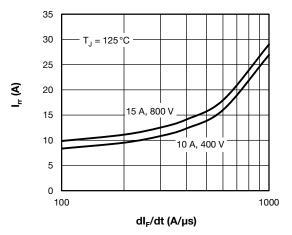


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg





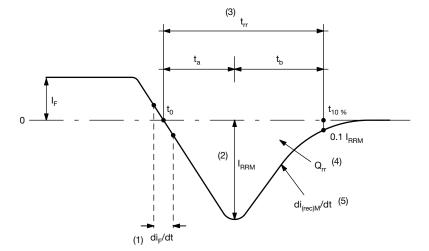


Fig. 10 - Reverse Recovery Waveform and Definitions

- Notes
- $^{(1)}$ di_F/dt rate of change of current through zero crossing $^{(2)}$ I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM} (4) Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}





ORDERING INFORMATION TABLE

Device code	VS-	с	5	Р	X	30	12	L	Н	N3
	1	2	3	4	5	6	7	8	9	10
	1 ·	- Visł	nay Sem	niconduc	ctors pro	oduct				
	2 ·	- C =	commo	on catho	de					
	3.	- 5 =	FRED g	eneratio	on 5					
	4 -	· Pac	kage: P	= TO-24	47AD 31	L				
	5	- X =	hyperfa	st recov	very					
	6	- Cur	rent rati	ng (30 =	= 30 A)					
	7	- Vol	tage rati	ng (12 =	= 1200 V	/)				
	8	L=	long lea	ad						
	9 -	• H=	AEC-Q	101 qua	lified					
	10 -	- Env	ironmer	ntal digit	:					
		N3	= halog	en-free,	RoHS-o	complia	nt, and	totally l	ead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-CPX3012LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95626					
Part marking information	www.vishay.com/doc?95007				



TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	5.46 BSC		5 BSC	
ØК	0.2	254	0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

Notes

- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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